Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1 .	94341	TFT (thin near film near transistor)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 14:29
S2	93925	(poly near (Si silicon)) ((poly near crystal\$4) near (silicon si)) ((poly\$1crystal\$4) near (silicon si))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 14:41
S3	230576	side\$1wall	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 14:46
S4	27920	LDD (lightly with doped with (drain source))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 14:47
S5	398	S1 and S2 and S3 and S4	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/08/30 14:50
S12	398	S8 and S9 and S10 and S11	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:03
S11	27920	LDD (lightly with doped with (drain source))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:03
S10	230576	side\$1wall	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:03
S9	93925	(poly near (Si silicon)) ((poly near crystal\$4) near (silicon si)) ((poly\$1crystal\$4) near (silicon si))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:03
S8	94341	TFT (thin near film near transistor)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:03
S13	247	S12 and S7	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:04

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S14	14	("4946799"   "5013675"   "5015595"   "5066613"   "5292675"   "5424230").PN. OR ("5786241").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/30 17:14
S15	46	("5073514"   "5089432"   "5091763"   "5108939"   "5200351"   "5358879").PN. OR ("5498555").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/30 17:17
S16	2	"US 20060071352"	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2006/08/30 17:22
S17	. 62	("4172260"   "4463491"   "4652897"   "4672419"   "4737828"   "4788663"   "4818715"   "4843023"   "4868617"   "4949136"   "4951100"   "4952825"   "4968639"   "4994404"   "5015598"   "5091763"   "5153145"   "5168072"   "5216268"   "5241203"   "5258319"   "5274261"   "5324974"   "5332914"   "5334870"   "5371394"   "5386133"   "5405791"   "5422506"   "5444282"   "5473184"   "5477070"   "5498555"   "5608240"   "5663586"   "5719425"   "5766969"   "5793089"   "5837572").PN. OR ("5895955").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/30 17:25
S18	12	("5324974"   "5895955"   "5920104"   "5925912"   "5936279"   "5952700"   "5990530"   "6040222").PN. OR ("6492665"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/30 17:32
S20		"20050272189"	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:49
S7	424108	spacer	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 17:59
S23	193	S22 and S11	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 18:00
S22	900	S21 and S8	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 18:00
S21	29930	spacer near3 (metal doped dopant semi\$1conduct\$3 conduct\$3)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/30 18:00
S24	39	("4447272"   "4951100"   "5102813"   "5292675"   "5306651"   "5466617"   "5476802"   "5504020"   "5508209"   "5523257"). PN. OR ("5719065").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 10:50
S26	<b>93976</b>	(poly near (Si silicon)) ((poly near crystal\$4) near (silicon si)) ((poly\$1crystal\$4) near (silicon si))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 14:56
S25	1362	((gate with overlap\$4 with lightly with doped with (drain sourece)) (gate with overlap\$4 with LDD) GOLDD) and TFT	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 14:56

S29	230754	side\$1wall	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 14:57
S28	424409	spacer	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/08/31 14:57
S27	1275	S25 and (S26 metal\$3)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 14:57
S30	. 73	S27 and S28 and S29	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 14:58
S31	21	("3933529"   "4727038"   "5247190"   "5323042"   "5399502"   "5594569"   "5643826"   "5693959"   "5719588"   "5912492"   "5923962"   "6166396"   "6180957"   "6198133"   "6281552"). PN. OR ("6518594").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 15:14
S32	16	("5015599"   "5247190"   "5399502"   "5643826"   "5923962"). PN. OR ("6512271").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 15:22
S33	76	(("5459090") or ("6528854") or ("20010030322") or ("20010035526") or ("20010041392") or ("20010052950") or ("20010055841") or ("20020006705") or ("20020008797") or ("20020016028") or ("20020024051") or ("20020028544") or ("20020070382") or ("20020102783") or ("20020110941") or ("20020158288") or ("20030094614") or ("5049514") or ("5079617") or ("5413961") or ("5432108") or ("5445987") or ("5473184") or ("5687113") or ("5767006") or ("6180502") or ("6274087") or ("6495406") or ("6335231") or ("6392628") or ("6559036")).PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/31 15:46
S34	16	("5015599"   "5247190"   "5399502"   "5643826"   "5923962"). PN. OR ("6512271").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 16:24
S35 .	43	("4818715"   "4837180"   "4906589"   "4907048"   "4925807"   "4963504"   "4971922").PN. OR ("5015599").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 16:26
S37	25	("3933529"   "4963504"   "5015599"   "5182619"   "5247190"   "5323042"   "5399502"   "5412240"   "5482871"   "5567966"   "5594569"   "5623157"   "5643826"   "5693959"   "5719588"   "5773330"   "5912492"   "5923962"   "6166396"   "6180957"   "6198133"   "6259120"   "6259138"   "6259144"   "6281552"). PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 16:32
S36	45	("3933529"   "4963504"   "5015599"   "5182619"   "5247190"   "5323042"   "5399502"   "5412240"   "5482871"   "5567966"   "5594569"   "5623157"   "5643826"   "5693959"   "5719588"   "5773330"   "5912492"   "5923962"   "6166396"   "6180957"   "6198133"   "6259120"   "6259138"   "6259144"   "6281552"). PN. OR ("6501098").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/31 16:32
S39	5	09/441026	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 16:37

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S38	2	("20020139980").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/31 16:37
S6	11	(("6166398") or ("5217913") or ("5498555") or ("5786241")).PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/07 14:17
S40	32	("4049477"   "4520553"   "4727038"   "4925807"   "4952993"   "4954867"   "4978628").PN. OR ("5217913").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/20 18:10
S41 ·	25	("4211601"   "4226665"   "4298443"   "4310380"   "4314875"   "4498953"   "4624882"   "5023204"   "5091763"   "5217913"   "5223457"   "5259922"   "5358879"   "5426327"   "5770506"   "5851861"   "5993614"   "6033990").PN. OR ("6284577"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/10/20 18:20
S42	2	("5015599").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/20 18:21
S19	16	GOLDD with TFT	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 12:29
S43	1086	(G\$10\$1L\$1D\$1D (gate with overlap\$3 with (L\$1D\$1D (lightly with doped with (drain source))))) same (TFT (thin with film with transistor))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 12:31
S45	2255460	substrate	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 12:48
S46	<b>33783</b>	S44 with S45	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/10/22 12:49
S47	182	S43 and S46	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/10/22 12:51
S48	224664	L near shap\$2	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 12:52
S49	2	S47 and S48	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 13:51

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S50	2	09/700132	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 13:52
S52	1	WO00/54339.ptpn.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 14:18
S54		WO-200054339-\$.did.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 14:26
S53		pct/jp00/01441.pct.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/10/22 14:26
S55	1	2000-602021.NRAN.	DERWENT	OR	ON	2006/10/22 14:40
S56	1	JP-07202210-\$.did.	DERWENT	OR	ON	2006/10/22 14:56
S57	1	JP-09055508-\$.did.	DERWENT	OR	ON	2006/10/22 14:57
S59	3	("5523257") PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/22 15:17
S58	. 1	JP-07321329-\$.did.	DERWENT	OR	ON	2006/10/22 15:17
S51	9	"6624473"	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 15:34
S60	2	("6624473").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/22 15:35
S62	1	S60 and S61	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 15:37
S63	199919	(poly\$1Si) (poly\$1silicon) (poly near (Si silicon)) ((poly near crystal\$4) near (silicon si)) ((poly\$1crystal\$4) near (silicon si))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 15:42
S44	95005	(poly near (Si silicon)) ((poly near crystal\$4) near (silicon si)) ((poly\$1crystal\$4) near (silicon si))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 15:42

S65	1	S60 and S63	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 15:43
S64	5647889	S63 channel metal\$3 sputter\$3 dopant doped	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/22 15:43
S61	5625609	S44 channel metal\$3 sputter\$3 dopant doped	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/10/22 15:43
S67		("5719065").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/03 18:44
S69	<b>242815</b>	sputter\$3	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 14:04
S68	2554249	thick\$4	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 14:04
S73	9	S72 and S70	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 14:22
S72	635550	etch\$3	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 14:22
S71	6	S68 and S69 and S70	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 14:22
\$74		(US-20060071352-\$ or US-20050067618-\$ or US-20030096460-\$ or US-20050017242-\$ or US-20030038289-\$ or US-20040089878-\$). did. or (US-5786241-\$ or US-6166398-\$ or US-5217913-\$ or US-5498555-\$ or US-5525530-\$ or US-6610571-\$ or US-6492665-\$ or US-6791112-\$ or US-5208476-\$ or US-5851861-\$ or US-6835607-\$ or US-5200351-\$ or US-591763-\$ or US-6144071-\$ or US-5719068-\$ or US-5719065-\$ or US-6518594-\$ or US-6977394-\$ or US-5073514-\$ or US-6512271-\$ or US-5015595-\$ or US-6080607-\$ or US-5013675-\$ or US-6284577-\$ or US-5753957-\$ or US-6624473-\$).did. or (WO-2004040653-\$ or WO-200054339-\$ or GB-2354882-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2006/12/07 14:52

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S79	482428	conform\$3	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 14:53
S77	7729	non\$1conform\$3	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 14:53
S81	504	S69 and \$3cvd and S77 and S79	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 15:09
S82	2	("6511912").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/12/07 15:10
S83	2	("5880007").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/07 15:28
S85	. 2	("5498555").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/07 15:33
S84	7	(("6166398") or ("5217913")).PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/07 15:33
S66	9	"6624473"	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 15:43
S88	1	S86 and S87	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 15:44
S87		("6624473").PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/07 15:44
S86	59360	upper and lower and gate and thick\$4 and thin\$4	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 15:44

C70	10	"CC24472"	US-PGPUB;	OR	ON	2006/12/07 15:44
S70	10	"6624473"	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	UK	ON .	2000/12/07 13.44
S90	98863	TFT (thin near film near transistor)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 16:22
S89	257	(438/596).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/07 16:22
S94	1246	S90 and S93	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 16:27
S91	22	S89 and S90	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 16:27
S93	226611	"L" near shape\$1	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 16:28
S96	247	S90 and S95	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/07 16:30
S95	29837	("L" near shape\$1) same (conduct\$4 metal dop\$4 poly\$1silicon)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2006/12/07 16:30